

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# JT6J15A-AS

## ROW DRIVER FOR A DOT MATRIX LCD

The JT6J15A-AS is a 80-channel-output row driver for a STN dot matrix LCD. The JT6J15A-AS features 28 V LCD drive voltage. The JT6J15A-AS is able to drive LCD panels with a duty ratio of up to 1/160.

As the JT6J15A-AS is equipped with a built-in voltage divider resistor, power supply operation amplifier, four and six-fold booster circuit, a contrast control circuit and a booster oscillator (oscillating capacitance is built in, and oscillating resistance is attached externally,) it is easy to structure a low power consumption LCD system by combining it with the JT6J14-AS column driver.

### FEATURES

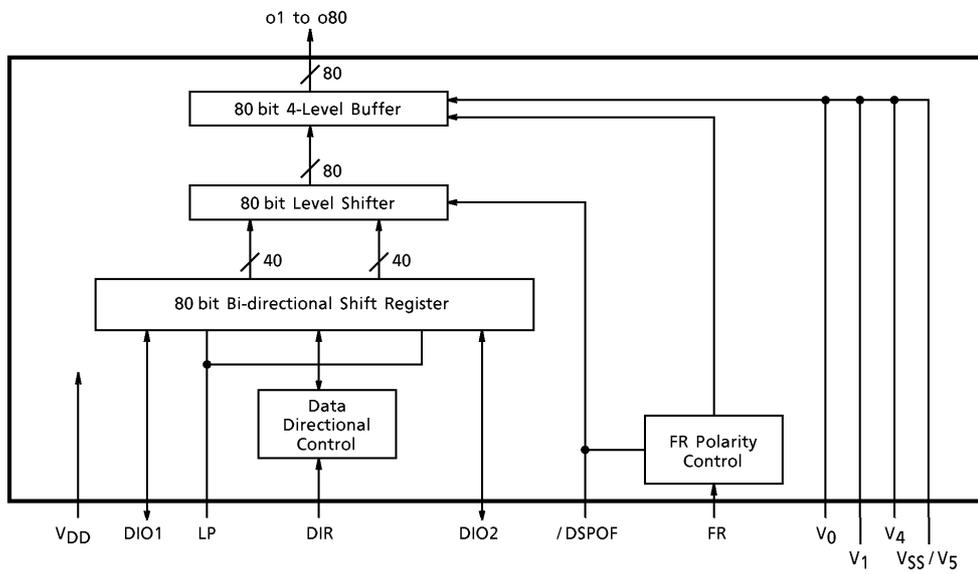
- Display duty application : to 1/160
- LCD drive signal : 80
- Data transfer : Two different styles of 1-bit bi-directional can be selected
  - ① COM80 ← COM1
  - ② COM80 → COM1
- Operating temperature : -20 to 75°C
- LCD drive output resistance : 1.5 kΩ MAX (Vo = 12.8 V, 1/7 to 1/14 Bias)
- Display-off function : When /DSPOF is "L", all LCD drive outputs (o1 to o80) remain at the V<sub>SS</sub>/V<sub>5</sub> level
- LCD drive voltage : 11 to 28 V (maximum drive voltage = 30 V)
- Power supply voltage : 2.7 to 5.5 V

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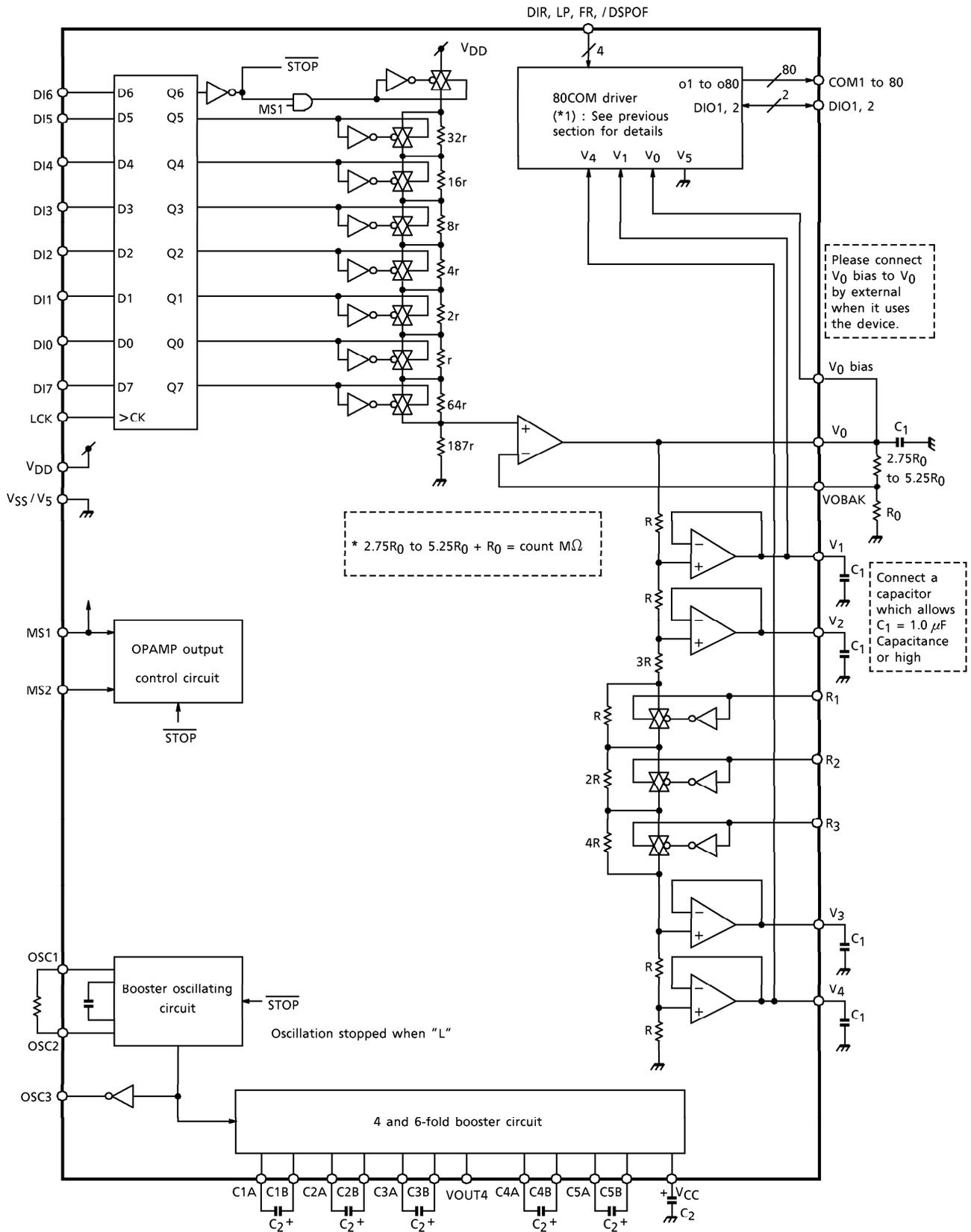
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**BLOCK DIAGRAM 1**

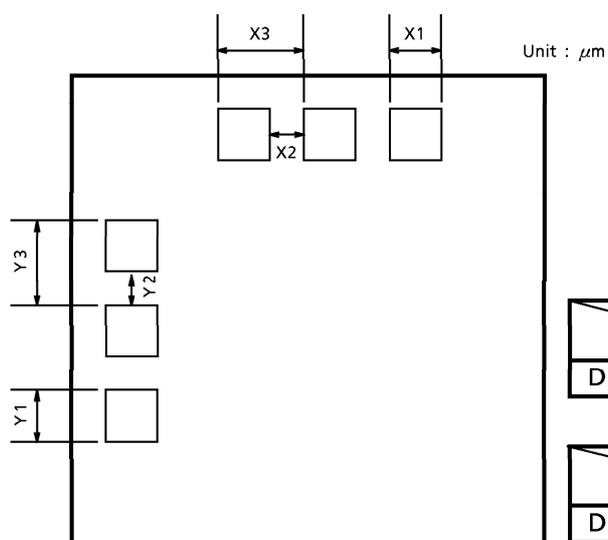
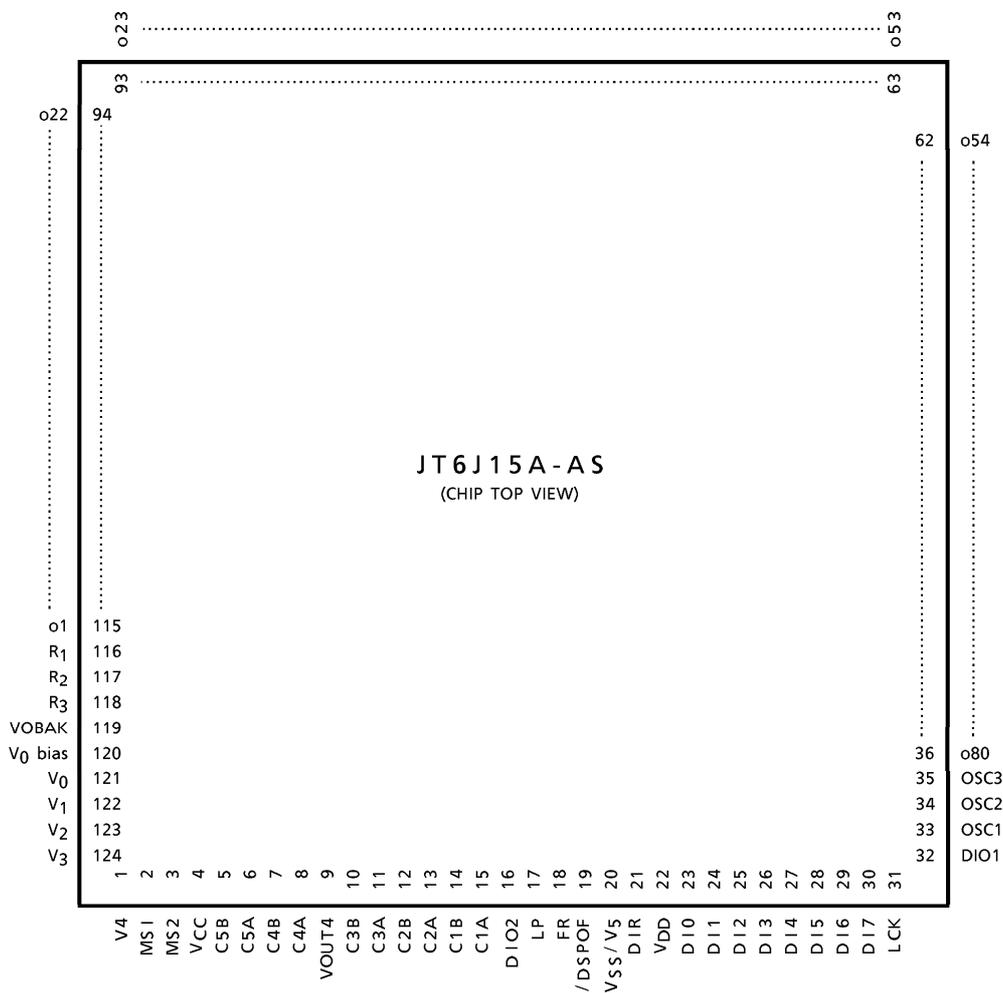
\*1...80 COM driver area



BLOCK DIAGRAM 2



**PIN ASSIGNMENT**



	X1	X2	X3
Dimensions ( $\mu\text{m}$ )	100	30	130

	Y1	Y2	Y3
Dimensions ( $\mu\text{m}$ )	100	30	130

**PAD COORDINATES**

Scribe width : 80 × 140 μm

Chip size : 4790 × 4850 μm (Including scribe width)

Number of PAD : 124 pcs

PAD size : 100 μm<sup>□</sup>

Palette edge coordinates 1 : -2355, -2355  
 2 : -2355, 2355  
 3 : 2355, 2355  
 4 : 2355, -2355

Chip edge coordinates 1 : -2395, -2425  
 2 : -2395, 2425  
 3 : 2395, 2425  
 4 : 2395, -2425

[Unit : μm]

No	PAD NAME	X POINT	Y POINT
1	V4	-1950	-2139
2	MS1	-1820	-2139
3	MS2	-1690	-2139
4	VCC	-1560	-2139
5	C5B	-1430	-2139
6	C5A	-1300	-2139
7	C4B	-1170	-2139
8	C4A	-1040	-2139
9	VOOUT4	-910	-2139
10	C3B	-780	-2139
11	C3A	-650	-2139
12	C2B	-520	-2139
13	C2A	-390	-2139
14	C1B	-260	-2139
15	C1A	-130	-2139
16	DIO2	0	-2139
17	LP	130	-2139
18	FR	260	-2139
19	/DSPOF	390	-2139
20	VSS/V5	520	-2139
21	DIR	650	-2139
22	VDD	780	-2139
23	DI0	910	-2139
24	DI1	1040	-2139
25	DI2	1170	-2139
26	DI3	1300	-2139
27	DI4	1430	-2139
28	DI5	1560	-2139
29	DI6	1690	-2139
30	DI7	1820	-2139
31	LCK	1950	-2139
32	DIO1	2139	-1950
33	OSC1	2139	-1820

No	PAD NAME	X POINT	Y POINT
34	OSC2	2139	-1690
35	OSC3	2139	-1560
36	o80	2139	-1430
37	o79	2139	-1300
38	o78	2139	-1170
39	o77	2139	-1040
40	o76	2139	-910
41	o75	2139	-780
42	o74	2139	-650
43	o73	2139	-520
44	o72	2139	-390
45	o71	2139	-260
46	o70	2139	-130
47	o69	2139	0
48	o68	2139	130
49	o67	2139	260
50	o66	2139	390
51	o65	2139	520
52	o64	2139	650
53	o63	2139	780
54	o62	2139	910
55	o61	2139	1040
56	o60	2139	1170
57	o59	2139	1300
58	o58	2139	1430
59	o57	2139	1560
60	o56	2139	1690
61	o55	2139	1820
62	o54	2139	1950
63	o53	1950	2139
64	o52	1820	2139
65	o51	1690	2139
66	o50	1560	2139

No	PAD NAME	X POINT	Y POINT
67	o49	1430	2139
68	o48	1300	2139
69	o47	1170	2139
70	o46	1040	2139
71	o45	910	2139
72	o44	780	2139
73	o43	650	2139
74	o42	520	2139
75	o41	390	2139
76	o40	260	2139
77	o39	130	2139
78	o38	0	2139
79	o37	-130	2139
80	o36	-260	2139
81	o35	-390	2139
82	o34	-520	2139
83	o33	-650	2139
84	o32	-780	2139
85	o31	-910	2139
86	o30	-1040	2139
87	o29	-1170	2139
88	o28	-1300	2139
89	o27	-1430	2139
90	o26	-1560	2139
91	o25	-1690	2139
92	o24	-1820	2139
93	o23	-1950	2139
94	o22	-2139	1950
95	o21	-2139	1820

No	PAD NAME	X POINT	Y POINT
96	o20	-2139	1690
97	o19	-2139	1560
98	o18	-2139	1430
99	o17	-2139	1300
100	o16	-2139	1170
101	o15	-2139	1040
102	o14	-2139	910
103	o13	-2139	780
104	o12	-2139	650
105	o11	-2139	520
106	o10	-2139	390
107	o9	-2139	260
108	o8	-2139	130
109	o7	-2139	0
110	o6	-2139	-130
111	o5	-2139	-260
112	o4	-2139	-390
113	o3	-2139	-520
114	o2	-2139	-650
115	o1	-2139	-780
116	R <sub>1</sub>	-2139	-910
117	R <sub>2</sub>	-2139	-1040
118	R <sub>3</sub>	-2139	-1170
119	VOBAK	-2139	-1300
120	V <sub>0</sub> bias	-2139	-1430
121	V <sub>0</sub>	-2139	-1560
122	V <sub>1</sub>	-2139	-1690
123	V <sub>2</sub>	-2139	-1820
124	V <sub>3</sub>	-2139	-1950

## PIN FUNCTIONS

PIN NAME	I/O	FUNCTIONS	LEVEL
o1 to o80	Output	Output for LCD drive signal	$V_0$ to $V_{SS}/V_5$
DIO1, DIO2	I/O	Input/Output for shift data	$V_{DD}$ to $V_{SS}/V_5$
LP	Input	(Shift Clock Pulse) Input for shift clock pulse	
FR	Input	(Frame) Input for frame signal	
DIR	Input	(Direction) Input for data flow direction select	
/DSPOF	Input	(Display Off) Display off pin "L" : Display-off mode, (o1 to o80) remain at the $V_{SS}/V_5$ level. "H" : Display-on mode, (o1 to o80) are operational.	
DIO to DI7	Input	Data bus : For contrast control usage Contrast adjustments are variable between 128 stages with the DIO to DI5 and DI7 data. DI6 : When "H": Stops the booster's oscillation frequency and turns the power supply ( $V_{DD}$ ) to the contrast controller off When "L": Operates the booster circuit and contrast controller circuit	
LCK	Input	Data bus loading clock Synchronized during rising and loaded internally.	
R1 to R3	Input	Bias set-up pin (bias settings possible between 1/7 and 1/14)	
OSC1/OSC2	Input	Booster oscillation pin Resistors connected to these pins when the internal clock is operating (100 k $\Omega$ between OSC1 and OSC2). The clock is input to OSC1 when the external clock is operating.	
OSC3	Output	Booster oscillating output pin The OSC3 pin is connected to another IC's OSC1 when the booster's oscillating frequency is shared with multiple connections.	
MS1/MS2	Input	Master/slave switching pin	—
CnA to CnB	—	Terminal for connecting external condensers (n = 1 to 5) Connect a booster capacitor which allows about $C_2 = 3.3 \mu\text{F}$ capacitance between CnA and CnB.	
VOU4	—	Booster voltage output pin (4-fold booster) Connect VOU4 and $V_{CC}$ when use of 4-fold booster.	
$V_{CC}$	—	LCD drive voltage pin (operation amplifier drive voltage, 6-fold booster terminal)	
$V_{DD}$	—	Power supply for internal logic	
$V_{SS}/V_5$	—	Power supply for internal logic	
VOBAK	—	Voltage amplifier circuit	
$V_0, V_1, V_2, V_3, V_4, V_0$ bias	—	Power supply for LCD drive circuit Connect an external capacitor which allows $C_1 = 1.0 \mu\text{F}$ capacitance or high to AMP output.	

**RELATIONSHIP BETWEEN FR, DATA INPUT AND OUTPUT LEVELS**

FR	INPUT DATA (DIO1, DIO2)	/DSPOF	OUTPUT LEVEL
H	L	H	V <sub>4</sub>
H	H	H	V <sub>0</sub> bias
L	L	H	V <sub>1</sub>
L	H	H	V <sub>SS</sub> /V <sub>5</sub>
(*)	(*)	L	V <sub>SS</sub> /V <sub>5</sub>

(\*) : Don't Care

**DATA INPUT FORMAT**

DIR	DATA TRANSFER DIRECTION	DATA INPUT TERMINALS	
		DIO1	DIO2
H	o1 → o80	Input	Output
L	o80 → o1	Output	Input

**OPERATION AMPLIFIER OUTPUT CONTROL CIRCUIT**

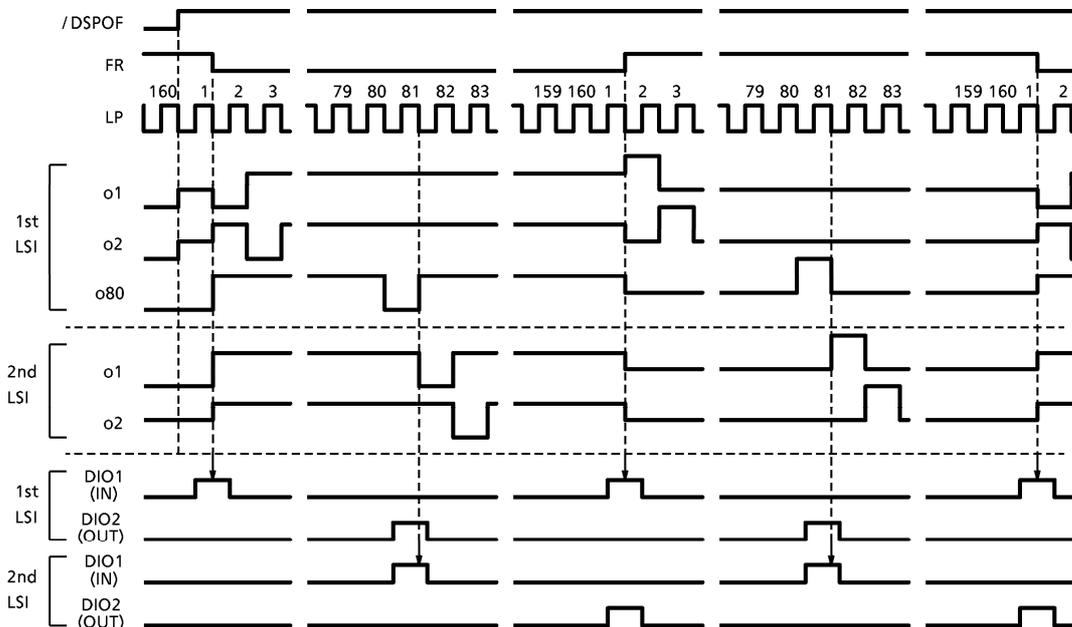
MS1	MS2	/STOP	MODE	BOOSTER OSCILLATIONS	BOOSTER	V <sub>0</sub> OUTPUT	V <sub>1</sub> , V <sub>4</sub> OUTPUT	V <sub>2</sub> , V <sub>3</sub> OUTPUT
L	*1	L	Slave mode (The booster circuit is driven and V <sub>CC</sub> voltage generated. V <sub>0</sub> , V <sub>1</sub> , V <sub>2</sub> , V <sub>3</sub> and V <sub>4</sub> are supplied from an external source)	—	Booster stopped	Output CUT, PD Tr ON		Output CUT, PD Tr ON
		H		External clock	Booster operating	Output CUT, PD Tr OFF (supplied from external source)		Output CUT, PD Tr ON
H	L	L	Master mode 1 (V <sub>0</sub> is output from the V <sub>CC</sub> voltage generating through driving the booster circuit. V <sub>1</sub> , V <sub>2</sub> , V <sub>3</sub> and V <sub>4</sub> are supplied from an external source)	Oscillations stopped	Booster stopped	Output CUT, PD Tr ON	Output CUT, PD Tr ON	Output CUT, PD Tr ON
		H		Oscillations operating	Booster operating	Output ON, PD Tr OFF (supplied to internal / external sources)	Output cut, PD Tr OFF (supplied from external source)	Output CUT, PD Tr ON
H	H	L	Master mode 2 V <sub>0</sub> , V <sub>1</sub> , V <sub>2</sub> , V <sub>3</sub> and V <sub>4</sub> are output from the V <sub>CC</sub> voltage generating through driving the booster circuit.)	Oscillations stopped	Booster stopped	Output CUT, PD Tr ON		Output CUT, PD Tr ON
		H		Oscillations operating	Booster operating	Output ON, PD Tr OFF (supplied to internal / external sources)		Output ON, PD Tr OFF (supplied to external source)

PD : Pull Down

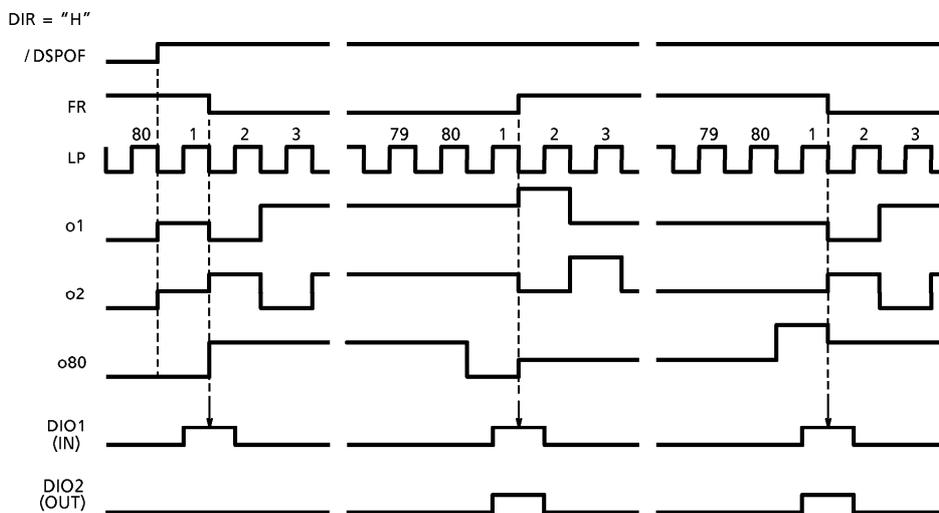
(\*1) : Connect to V<sub>DD</sub> or V<sub>SS</sub>/V<sub>5</sub>

**TIMING DIAGRAM**

- Use of JT6J15A-AS 2 pcs (DIR = "H")



- Use of JT6J15A-AS 1 pc (DIR = "H")



**ABSOLUTE MAXIMUM RATINGS**

(Ensure that the following conditions are maintained,  $V_0 \geq V_1 \geq V_2 \geq V_3 \geq V_4 \geq V_{SS} / V_5 = 0V$ )

CHARACTERISTIC	SYMBOL	RATING	UNIT	PIN NAME
Power Supply Voltage (1)	$V_{DD}$	-0.3 to 6.0	V	$V_{DD}$
Power Supply Voltage (2)	$V_{CC}$	$V_{DD}$ to 30.0	V	$V_{CC}$
Input Voltage	$V_{in}$	-0.3 to $V_{DD} + 0.3$	V	(*2)
Operating Temperature	$T_{opr}$	-20 to 75	°C	—
Storage Temperature	$T_{stg}$	-40 to 125	°C	—

(\*2) : FR, LP, DIR, DIO1, DIO2, DI0 to DI7, LCK, R1 to R3, /DSPOF

## ELECTRICAL CHARACTERISTICS

## DC CHARACTERISTICS 1

(Unless otherwise noted,  $V_{SS} = 0\text{ V}$ ,  $V_{DD} = 2.7\text{ to }5.5\text{ V}$ ,  $V_0 = 11\text{ to }28\text{ V}$ ,  $T_a = -20\text{ to }75^\circ\text{C}$ )

ITEM	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT	PIN NAME	
Supply Voltage (1)	$V_{DD}$		2.7	5.0	5.5	V	$V_{DD}$	
Supply Voltage (2)	$V_0$	$V_{CC} \geq V_0$	11	—	28	V	$V_0$	
Supply Voltage (3)	$V_{CC}$	$V_{CC} \geq V_0$	11	—	28	V	$V_{CC}$	
Input Voltage	"H" Level	$V_{IH}$	$0.8V_{DD}$	—	$V_{DD}$	V	(*3)	
	"L" Level	$V_{IL}$	0	—	$0.2V_{DD}$			
Output Voltage	"H" Level	$V_{OH}$	$I_{OH} = -0.5\text{ mA}$	$V_{DD} - 0.5$	—	$V_{DD}$	V	DIO1, DIO2
	"L" Level	$V_{OL}$	$I_{OL} = 0.5\text{ mA}$	0	—	0.5		
Output Resistance	"H" Level	$R_{OH}$	$V_{OUT} = V_0 - 0.5\text{ V}$ (*4)	—	—	1.5	k $\Omega$	o1 to o80
	"M" Level	$R_{OM}$	$V_{OUT} = V_1 \pm 0.5\text{ V}$ (*4)	—	—	1.5		
		$R_{OM}$	$V_{OUT} = V_4 \pm 0.5\text{ V}$ (*4)	—	—	1.5		
	"L" Level	$R_{OL}$	$V_{OUT} = V_{SS}/V_5 + 0.5\text{ V}$ (*4)	—	—	1.5		
Input Current	$I_{IL1}$	$V_{IN} = 0\text{ to }V_{DD}$	-1.0	—	1.0	$\mu\text{A}$	(*3)	
Output Voltage (with a 4-fold booster)	$V_{O1}$	$V_{DD} = 5.0\text{ V}$ (*5)	17.64			V	$V_{CC}$	
Output Voltage (with a 6-fold booster)	$V_{O2}$	$V_{DD} = 3.0\text{ V}$ (*5)	14.0					
Current Consumption	$I_{DD\text{ OPE}}$	$V_{DD} = 5.0\text{ V}$	When operating (*6)		1.1	1.5	mA	$V_{DD}$
		$V_{DD} = 3.0\text{ V}$	When operating (*7)		1.2	1.8		
	$I_{DD\text{ LEAK}}$	$V_{DD} = 5.5\text{ V}$	When no operating			1.0	$\mu\text{A}$	$V_0\text{ bias}$
	$I_0\text{ bias OPE}$	$V_0 = 15.0\text{ V}$	When operating (*8)		10	25		
	$I_{CC\text{ LEAK}}$		When no operating (*9)			1.0		

(\*3) : FR, LP, DIR, DIO1, DIO2, DI0 to DI7, LCK, R1 to R3, /DSPOF

(\*4) :  $V_0 = 12.8\text{ V}$ , 1/7 to 1/14 bias(\*5) :  $I_{Load} = 450\ \mu\text{A}$ , external  $C_2 = 3.3\ \mu\text{F}$ , when using COM 1 pc  $T_a = 25^\circ\text{C}$ , OP-AMP ON(\*6) : Oscillation resistance = 100 k $\Omega$ , DC/DC ON, OP-AMP ON, 1/10 bias, contrast MAX  
fLP = 11.2 kHz, fFR = 35 Hz, fFP = 70 Hz,  $V_{DD} = 5.0\text{ V}$ , 4 booster, no load(\*7) : Oscillation resistance = 100 k $\Omega$ , DC/DC ON, OP-AMP ON, 1/10 bias, contrast MAX  
fLP = 11.2 kHz, fFR = 35 Hz, fFP = 70 Hz,  $V_{DD} = 3.0\text{ V}$ , 6 booster, no load(\*8) : LCD drive current : fFR = 35 Hz, fLP = 11.2 kHz, fFP = 70 Hz, 1/10 bias, no load,  
MS1 = "L", /STOP = "L"

(\*9) : MS1 = "L", /STOP = "L"

fFP : Screen switching frequency

DC CHARACTERISTICS 2

LOAD REGULATIONS CHARACTERISTICS 1 ... no load /MAX load Offset

TEST CONDITIONS :  $V_{CC} = 18\text{ V}$  (Outside applied voltage), Contrast = 62 (DI1 to DI5 = "H", DI0, DI7 = "L"), External capacitor for AMP :  $C_1 = 1.0\ \mu\text{F}$   
 Gain Resistance = 4 times ( $3R_0, R_0$ ), 1/10 bias,  $V_{DD} = 5.0\text{ V}$ ,  $T_a = -20$  to  $75\text{ }^\circ\text{C}$ ,  
 The  $V_1$  to  $V_4$  OFFSET spec is defined toward the ideal voltage calculated from the  $V_0$  voltage.

OFFSET SPECIFIED VALUE

	NO LOAD		MAX LOAD		MAX LOAD (REVERSE ELECTRIC CURRENT)		UNIT
	MIN	MAX	MIN	MAX	MIN	MAX	
$V_0$	14.6	15.6	14.50	15.50	—	—	V
$V_1$	- 100	90	- 110	75	- 110	110	mV
$V_2$	- 65	65	- 50	75	- 110	110	mV
$V_3$	- 70	70	- 85	50	- 110	110	mV
$V_4$	- 55	50	- 45	65	- 110	110	mV
X	- 220	190	- 255	145	—	—	mV
Y	- 120	130	- 170	85	—	—	mV
$\Delta V$	- 210	190	- 300	120	—	—	mV

LOAD CONDITIONS

	NO LOAD	MAX LOAD	MAX LOAD (REVERSE ELECTRIC CURRENT)	UNIT
$I_0$	0	- 300	—	$\mu\text{A}$
$I_1$	0	- 50	50	$\mu\text{A}$
$I_2$	0	200	- 100	$\mu\text{A}$
$I_3$	0	- 200	100	$\mu\text{A}$
$I_4$	0	50	- 50	$\mu\text{A}$

Non-lighting BIAS  
 $X = (V_1 - V_2) - (V_0 - V_1)$   
 $Y = (V_3 - V_4) - (V_4 - V_{SS})$

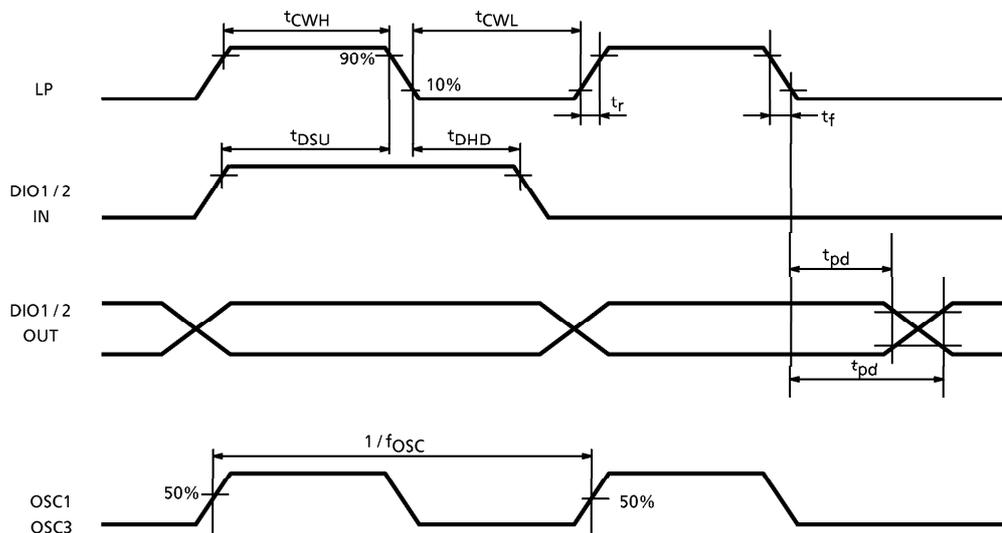
VOM balance  
 $\Delta V = X + Y$

$V_0$  to  $V_4$  are specified as follows

When the  $V_0$  voltage is set to the maximum voltage for the contrast with the DIO to DI7 data bus set to "H".

BIAS SET-UP VALUE	R <sub>1</sub>	R <sub>2</sub>	R <sub>3</sub>	V <sub>1</sub>	V <sub>2</sub>	V <sub>3</sub>	V <sub>4</sub>
1/7	H	H	H	6/7V <sub>0</sub>	5/7V <sub>0</sub>	2/7V <sub>0</sub>	1/7V <sub>0</sub>
1/8	L	H	H	7/8V <sub>0</sub>	6/8V <sub>0</sub>	2/8V <sub>0</sub>	1/8V <sub>0</sub>
1/9	H	L	H	8/9V <sub>0</sub>	7/9V <sub>0</sub>	2/9V <sub>0</sub>	1/9V <sub>0</sub>
1/10	L	L	H	9/10V <sub>0</sub>	8/10V <sub>0</sub>	2/10V <sub>0</sub>	1/10V <sub>0</sub>
1/11	H	H	L	10/11V <sub>0</sub>	9/11V <sub>0</sub>	2/11V <sub>0</sub>	1/11V <sub>0</sub>
1/12	L	H	L	11/12V <sub>0</sub>	10/12V <sub>0</sub>	2/12V <sub>0</sub>	1/12V <sub>0</sub>
1/13	H	L	L	12/13V <sub>0</sub>	11/13V <sub>0</sub>	2/13V <sub>0</sub>	1/13V <sub>0</sub>
1/14	L	L	L	13/14V <sub>0</sub>	12/14V <sub>0</sub>	2/14V <sub>0</sub>	1/14V <sub>0</sub>

**AC CHARACTERISTICS 1**



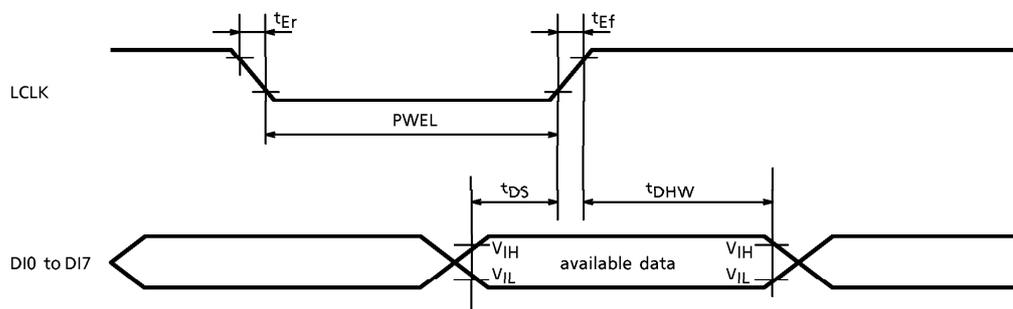
TEST CONDITIONS :  $t_C$  (one LP signal cycle) =  $t_{CWH} + t_{CWL} + t_r + t_f$   
 (Unless otherwise noted,  $V_{SS} = 0V$ ,  $V_{DD} = 2.7$  to  $5.5V$ ,  $V_{CC} = 11$  to  $28V$ ,  $T_a = -20$  to  $75^\circ C$ )

ITEM	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
LP Pulse Width	$t_{CWH}$	LP	30	—	—	ns
	$t_{CWL}$	LP	1	—	—	$\mu s$
Data Set-up Time	$t_{DSU}$	DIO1, DIO2	30	—	—	ns
Data Hold Time	$t_{DHD}$	DIO1, DIO2	5	—	—	
LP Rise/Fall Time	$t_r, t_f$	LP, FR, DIO1, DIO2	—	—	50	
Output Delay Time (*11)	$t_{pd}$	DIO1, DIO2	20	—	500	kHz
Oscillating Frequency	$f_{osc}$	OSC1 (*12)	25.5	—	42.5	
External Clock Frequency		OSC3	25.5	—	42.5	

(\*11) :  $C_L = 10$  pF

(\*12) : External resistance =  $100$  k $\Omega$  (between OSC1 and OSC2)

**AC CHARACTERISTICS 2**



**TEST CONDITIONS 1**

(Unless otherwise noted,  $V_{SS} = 0\text{ V}$ ,  $V_{DD} = 3.0\text{ V} \pm 10\%$ ,  $V_{CC} = 11\text{ to }28\text{ V}$ ,  $T_a = -20\text{ to }75^\circ\text{C}$ )

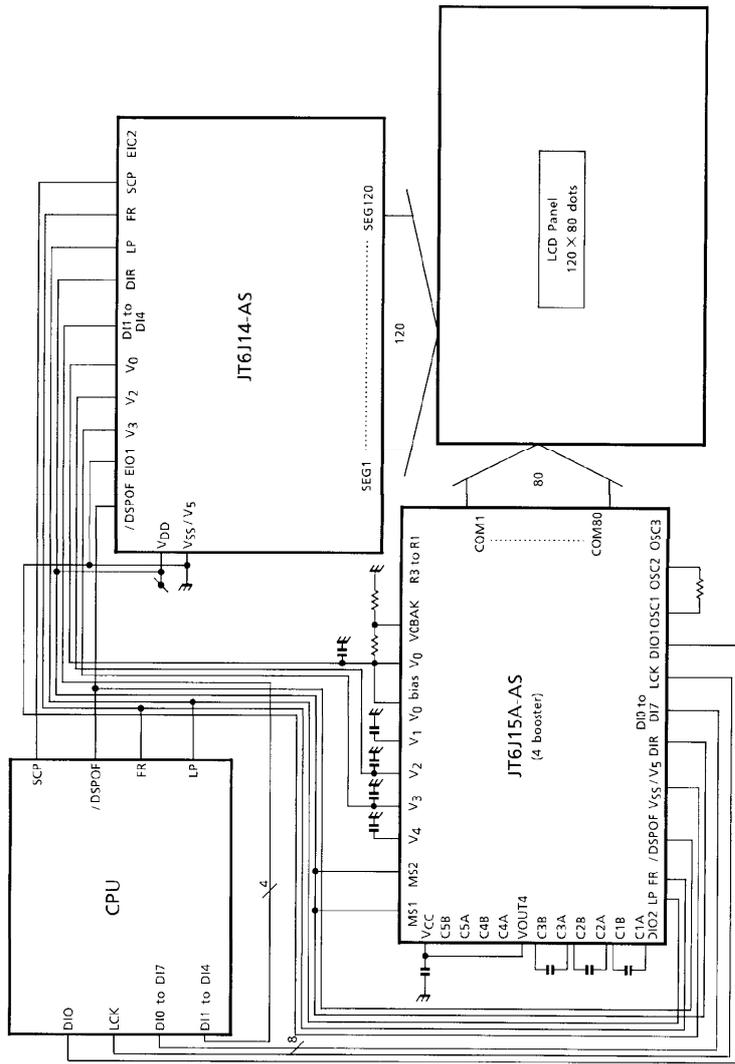
ITEM	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Enable Rise / Fall Time	$t_{Er} / t_{Ef}$				25	ns
Enable Pulse Width	PWEL		60			ns
Data Set-up Time	$t_{DS}$		60			ns
Data Hold Time	$t_{DHW}$		10			ns

**TEST CONDITIONS 2**

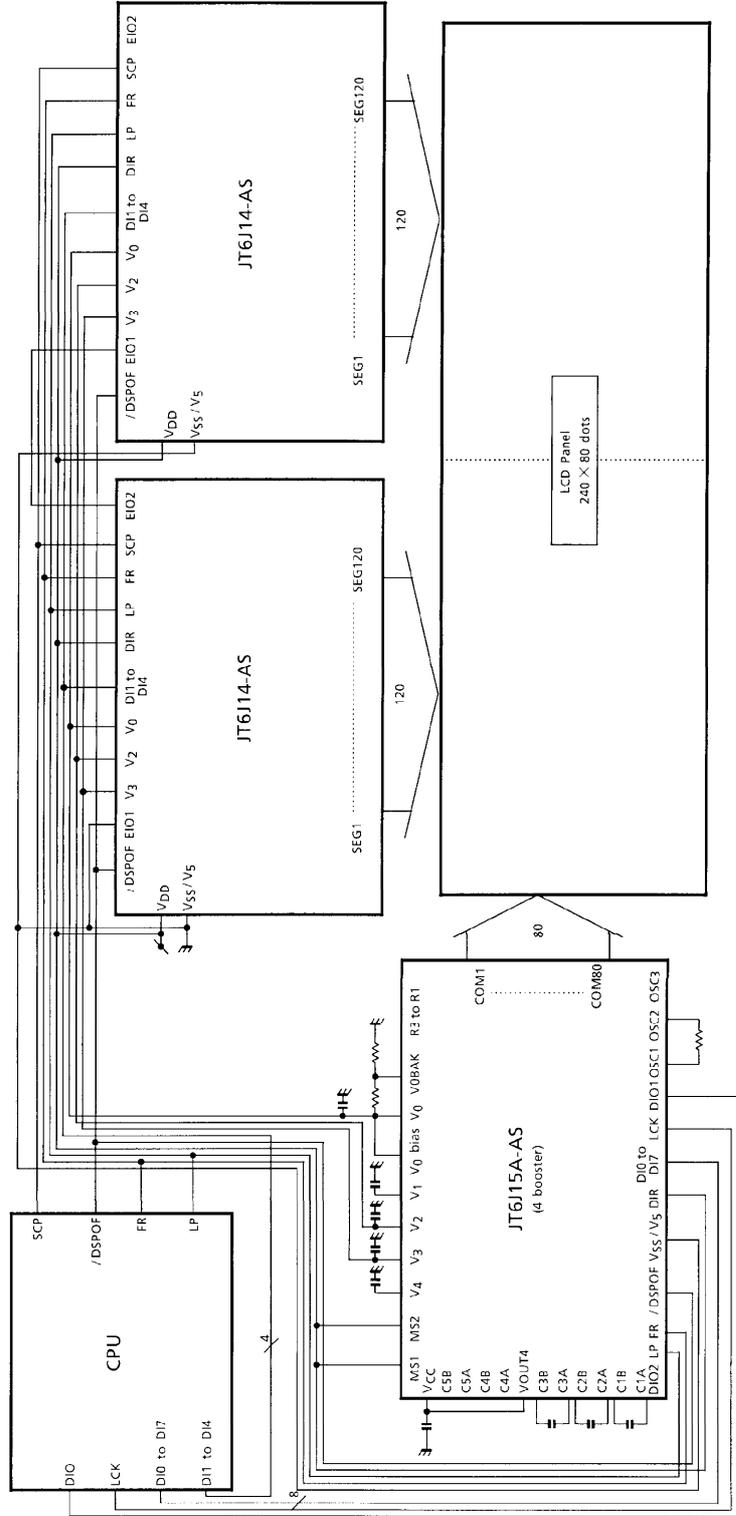
(Unless otherwise noted,  $V_{SS} = 0\text{ V}$ ,  $V_{DD} = 5.0\text{ V} \pm 10\%$ ,  $V_{CC} = 11\text{ to }28\text{ V}$ ,  $T_a = -20\text{ to }75^\circ\text{C}$ )

ITEM	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Enable Rise / Fall Time	$t_{Er} / t_{Ef}$				20	ns
Enable Pulse Width	PWEL		60			ns
Data Set-up Time	$t_{DS}$		60			ns
Data Hold Time	$t_{DHW}$		10			ns

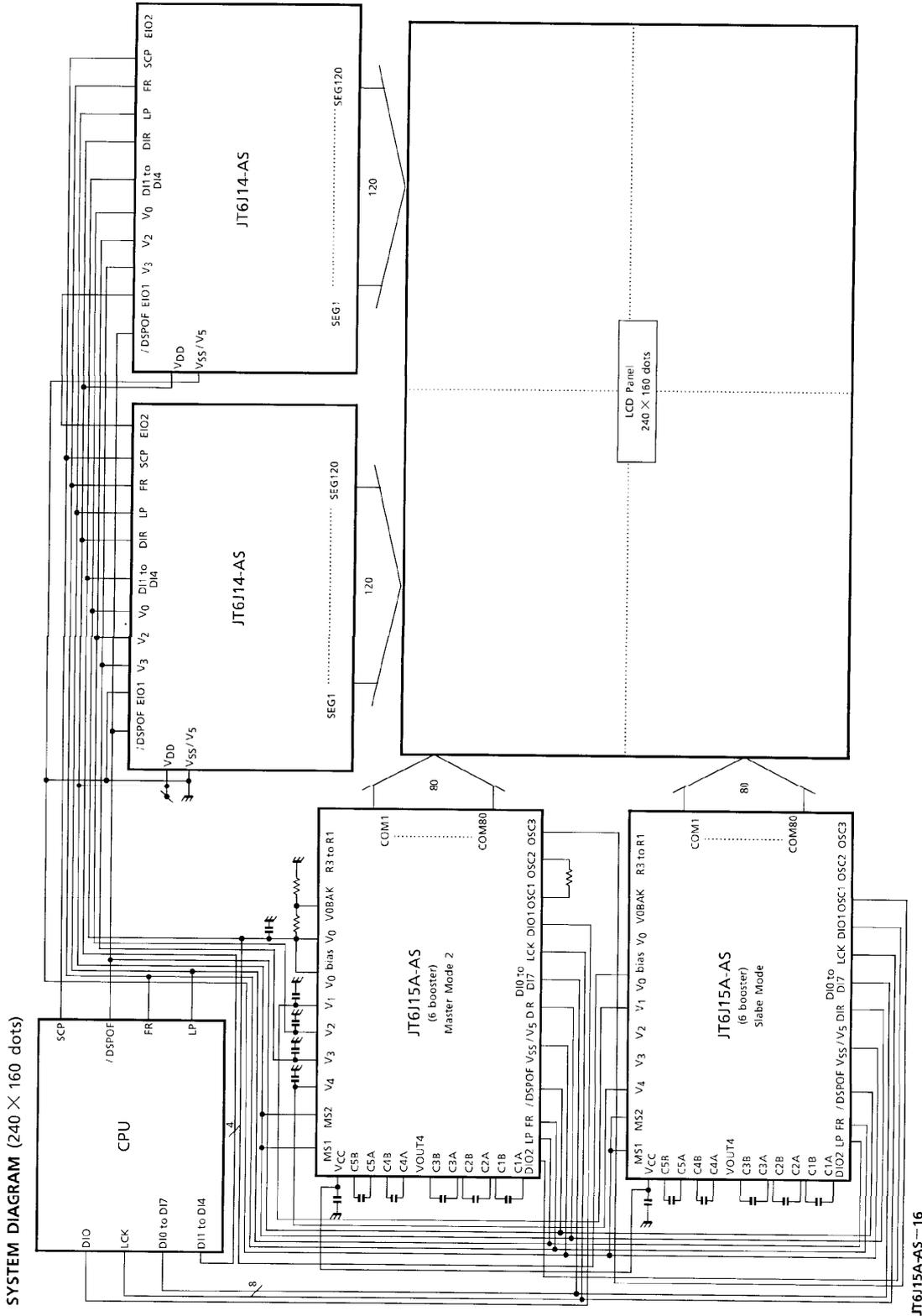
SYSTEM DIAGRAM (120 × 80 dots)



SYSTEM DIAGRAM (240 × 80 dots)



JT6J15A-AS - 15



JT6J15A-AS-16